

# J Joshua Yang

## List of Publications by Year in Descending Order

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**Version:** 2024-04-19

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The third column is the impact factor (IF) of the journal, and the fourth column is the number of citations of the article.

97  
papers

19,772  
citations

58  
h-index

105  
g-index

105  
ext. papers

24,164  
ext. citations

16.5  
avg, IF

7.16  
L-index

#	Paper	IF	Citations
97	Reset Switching Statistics of TaOx-Based Memristor. <i>Kluwer International Series in Electronic Materials: Science and Technology</i> , <b>2022</b> , 187-195		
96	Ta/HfO <sub>2</sub> -based Memristor and Crossbar Arrays for In-Memory Computing <b>2022</b> , 167-188		
95	Standards for the Characterization of Endurance in Resistive Switching Devices. <i>ACS Nano</i> , <b>2021</b> ,	16.7	36
94	A fully hardware-based memristive multilayer neural network. <i>Science Advances</i> , <b>2021</b> , 7, eabj4801	14.3	10
93	The secret order of disorder. <i>Nature Materials</i> , <b>2021</b> ,	27	1
92	Engineering Tunneling Selector to Achieve High Non-linearity for 1S1R Integration. <i>Frontiers in Nanotechnology</i> , <b>2021</b> , 3,	5.5	2
91	Roadmap on emerging hardware and technology for machine learning. <i>Nanotechnology</i> , <b>2021</b> , 32, 0120034	3.4	45
90	Integration and Co-design of Memristive Devices and Algorithms for Artificial Intelligence. <i>IScience</i> , <b>2020</b> , 23, 101809	6.1	20
89	A Memristor with Low Switching Current and Voltage for 1S1R Integration and Array Operation. <i>Advanced Electronic Materials</i> , <b>2020</b> , 6, 1901411	6.4	21
88	Neuronal realizations based on memristive devices <b>2020</b> , 407-426		
87	Power-efficient neural network with artificial dendrites. <i>Nature Nanotechnology</i> , <b>2020</b> , 15, 776-782	28.7	55
86	Gate-tunable van der Waals heterostructure for reconfigurable neural network vision sensor. <i>Science Advances</i> , <b>2020</b> , 6, eaba6173	14.3	66
85	Power-efficient combinatorial optimization using intrinsic noise in memristor Hopfield neural networks. <i>Nature Electronics</i> , <b>2020</b> , 3, 409-418	28.4	79
84	Resistive switching materials for information processing. <i>Nature Reviews Materials</i> , <b>2020</b> , 5, 173-195	73.3	318
83	A Low-Current and Analog Memristor with Ru as Mobile Species. <i>Advanced Materials</i> , <b>2020</b> , 32, e1904599	2.4	32
82	Fully hardware-implemented memristor convolutional neural network. <i>Nature</i> , <b>2020</b> , 577, 641-646	50.4	529
81	Brain-inspired computing with memristors: Challenges in devices, circuits, and systems. <i>Applied Physics Reviews</i> , <b>2020</b> , 7, 011308	17.3	105

80	Three-dimensional memristor circuits as complex neural networks. <i>Nature Electronics</i> , <b>2020</b> , 3, 225-232	28.4	112
79	An artificial spiking afferent nerve based on Mott memristors for neurorobotics. <i>Nature Communications</i> , <b>2020</b> , 11, 51	17.4	105
78	Bioinspired bio-voltage memristors. <i>Nature Communications</i> , <b>2020</b> , 11, 1861	17.4	79
77	Bridging Biological and Artificial Neural Networks with Emerging Neuromorphic Devices: Fundamentals, Progress, and Challenges. <i>Advanced Materials</i> , <b>2019</b> , 31, e1902761	24	220
76	In situ training of feed-forward and recurrent convolutional memristor networks. <i>Nature Machine Intelligence</i> , <b>2019</b> , 1, 434-442	22.5	93
75	Low-Voltage, CMOS-Free Synaptic Memory Based on LiTiO Redox Transistors. <i>ACS Applied Materials &amp; Interfaces</i> , <b>2019</b> , 11, 38982-38992	9.5	47
74	RRAM/memristor for computing <b>2019</b> , 539-583		2
73	Parallel programming of an ionic floating-gate memory array for scalable neuromorphic computing. <i>Science</i> , <b>2019</b> , 364, 570-574	33.3	296
72	Memristive crossbar arrays for brain-inspired computing. <i>Nature Materials</i> , <b>2019</b> , 18, 309-323	27	582
71	Artificial Neural Network (ANN) to Spiking Neural Network (SNN) Converters Based on Diffusive Memristors. <i>Advanced Electronic Materials</i> , <b>2019</b> , 5, 1900060	6.4	55
70	Reinforcement learning with analogue memristor arrays. <i>Nature Electronics</i> , <b>2019</b> , 2, 115-124	28.4	166
69	Understanding memristive switching via in situ characterization and device modeling. <i>Nature Communications</i> , <b>2019</b> , 10, 3453	17.4	138
68	Mott-transition-based RRAM. <i>Materials Today</i> , <b>2019</b> , 28, 63-80	21.8	24
67	Reservoir Computing Using Diffusive Memristors. <i>Advanced Intelligent Systems</i> , <b>2019</b> , 1, 1900084	6	65
66	CMOS-integrated memristive non-volatile computing-in-memory for AI edge processors. <i>Nature Electronics</i> , <b>2019</b> , 2, 420-428	28.4	74
65	Learning with Resistive Switching Neural Networks <b>2019</b> ,		4
64	Experimental Demonstration of Conversion-Based SNNs with 1T1R Mott Neurons for Neuromorphic Inference <b>2019</b> ,		10
63	Memristor crossbar arrays with 6-nm half-pitch and 2-nm critical dimension. <i>Nature Nanotechnology</i> , <b>2019</b> , 14, 35-39	28.7	231

62	Long short-term memory networks in memristor crossbar arrays. <i>Nature Machine Intelligence</i> , <b>2019</b> , 1, 49-57	22.5	176
61	Emerging Memory Devices for Neuromorphic Computing. <i>Advanced Materials Technologies</i> , <b>2019</b> , 4, 1800589	6.4	181
60	Recommended Methods to Study Resistive Switching Devices. <i>Advanced Electronic Materials</i> , <b>2019</b> , 5, 1800143	6.4	297
59	Robust memristors based on layered two-dimensional materials. <i>Nature Electronics</i> , <b>2018</b> , 1, 130-136	28.4	348
58	An artificial nociceptor based on a diffusive memristor. <i>Nature Communications</i> , <b>2018</b> , 9, 417	17.4	183
57	Fully memristive neural networks for pattern classification with unsupervised learning. <i>Nature Electronics</i> , <b>2018</b> , 1, 137-145	28.4	511
56	Threshold Switching of Ag or Cu in Dielectrics: Materials, Mechanism, and Applications. <i>Advanced Functional Materials</i> , <b>2018</b> , 28, 1704862	15.6	168
55	Memristor-Based Analog Computation and Neural Network Classification with a Dot Product Engine. <i>Advanced Materials</i> , <b>2018</b> , 30, 1705914	24	339
54	A compact model for selectors based on metal doped electrolyte. <i>Applied Physics A: Materials Science and Processing</i> , <b>2018</b> , 124, 1	2.6	2
53	Inducing tunable switching behavior in a single memristor. <i>Applied Materials Today</i> , <b>2018</b> , 11, 280-290	6.6	18
52	Large Memristor Crossbars for Analog Computing <b>2018</b> ,		6
51	Capacitive neural network with neuro-transistors. <i>Nature Communications</i> , <b>2018</b> , 9, 3208	17.4	132
50	Pulse-Width Modulation based Dot-Product Engine for Neuromorphic Computing System using Memristor Crossbar Array <b>2018</b> ,		10
49	Efficient and self-adaptive in-situ learning in multilayer memristor neural networks. <i>Nature Communications</i> , <b>2018</b> , 9, 2385	17.4	371
48	Analogue signal and image processing with large memristor crossbars. <i>Nature Electronics</i> , <b>2018</b> , 1, 52-59	28.4	550
47	A provable key destruction scheme based on memristive crossbar arrays. <i>Nature Electronics</i> , <b>2018</b> , 1, 548-554	28.4	32
46	Memristor-CMOS Analog Coprocessor for Acceleration of High-Performance Computing Applications. <i>ACM Journal on Emerging Technologies in Computing Systems</i> , <b>2018</b> , 14, 1-30	1.7	2
45	Review of memristor devices in neuromorphic computing: materials sciences and device challenges. <i>Journal Physics D: Applied Physics</i> , <b>2018</b> , 51, 503002	3	183

44	Artificial neural networks based on memristive devices. <i>Science China Information Sciences</i> , <b>2018</b> , 61, 1	3.4	9
43	Silicon Oxide (SiO): A Promising Material for Resistance Switching?. <i>Advanced Materials</i> , <b>2018</b> , 30, e1801187	17	105
42	In-Memory Computing with Memristor Arrays <b>2018</b> ,		12
41	Anatomy of Ag/Hafnia-Based Selectors with 10 Nonlinearity. <i>Advanced Materials</i> , <b>2017</b> , 29, 1604457	24	245
40	Organic electronics: Battery-like artificial synapses. <i>Nature Materials</i> , <b>2017</b> , 16, 396-397	27	24
39	An efficient analog Hamming distance comparator realized with a unipolar memristor array: a showcase of physical computing. <i>Scientific Reports</i> , <b>2017</b> , 7, 40135	4.9	22
38	A niobium oxide-tantalum oxide selector-memristor self-aligned nanostack. <i>Applied Physics Letters</i> , <b>2017</b> , 110, 103102	3.4	17
37	Characteristics and transport mechanisms of triple switching regimes of TaOx memristor. <i>Applied Physics Letters</i> , <b>2017</b> , 110, 173504	3.4	20
36	Three-dimensional crossbar arrays of self-rectifying Si/SiO/Si memristors. <i>Nature Communications</i> , <b>2017</b> , 8, 15666	17.4	115
35	Mimicking Classical Conditioning Based on a Single Flexible Memristor. <i>Advanced Materials</i> , <b>2017</b> , 29, 1602890	24	93
34	Flexible three-dimensional artificial synapse networks with correlated learning and trainable memory capability. <i>Nature Communications</i> , <b>2017</b> , 8, 752	17.4	176
33	A novel true random number generator based on a stochastic diffusive memristor. <i>Nature Communications</i> , <b>2017</b> , 8, 882	17.4	180
32	Truly Electroforming-Free and Low-Energy Memristors with Preconditioned Conductive Tunneling Paths. <i>Advanced Functional Materials</i> , <b>2017</b> , 27, 1702010	15.6	56
31	Memristors with diffusive dynamics as synaptic emulators for neuromorphic computing. <i>Nature Materials</i> , <b>2017</b> , 16, 101-108	27	1201
30	An energy-efficient and high-throughput bitwise CNN on sneak-path-free digital ReRAM crossbar <b>2017</b> ,		12
29	Quantized conductance coincides with state instability and excess noise in tantalum oxide memristors. <i>Nature Communications</i> , <b>2016</b> , 7, 11142	17.4	69
28	High-Speed and Low-Energy Nitride Memristors. <i>Advanced Functional Materials</i> , <b>2016</b> , 26, 5290-5296	15.6	177
27	Sub-10 nm Ta Channel Responsible for Superior Performance of a HfO2 Memristor. <i>Scientific Reports</i> , <b>2016</b> , 6, 28525	4.9	128

26	Trilayer Tunnel Selectors for Memristor Memory Cells. <i>Advanced Materials</i> , <b>2016</b> , 28, 356-62	24	83
25	Electrochemical metallization switching with a platinum group metal in different oxides. <i>Nanoscale</i> , <b>2016</b> , 8, 14023-30	7.7	33
24	Low-Power, Self-Rectifying, and Forming-Free Memristor with an Asymmetric Programming Voltage for a High-Density Crossbar Application. <i>Nano Letters</i> , <b>2016</b> , 16, 6724-6732	11.5	131
23	Memristive devices for computing. <i>Nature Nanotechnology</i> , <b>2013</b> , 8, 13-24	28.7	2406
22	A compact modeling of TiO <sub>2</sub> -TiO <sub>2-x</sub> memristor. <i>Applied Physics Letters</i> , <b>2013</b> , 102, 153503	3.4	32
21	Electrical performance and scalability of Pt dispersed SiO <sub>2</sub> nanometallic resistance switch. <i>Nano Letters</i> , <b>2013</b> , 13, 3213-7	11.5	146
20	State Dynamics and Modeling of Tantalum Oxide Memristors. <i>IEEE Transactions on Electron Devices</i> , <b>2013</b> , 60, 2194-2202	2.9	120
19	Engineering nonlinearity into memristors for passive crossbar applications. <i>Applied Physics Letters</i> , <b>2012</b> , 100, 113501	3.4	162
18	Continuous electrical tuning of the chemical composition of TaO(x)-based memristors. <i>ACS Nano</i> , <b>2012</b> , 6, 2312-8	16.7	100
17	Electronic structure and transport measurements of amorphous transition-metal oxides: observation of Fermi glass behavior. <i>Applied Physics A: Materials Science and Processing</i> , <b>2012</b> , 107, 1-11	2.6	47
16	Metal/TiO <sub>2</sub> interfaces for memristive switches. <i>Applied Physics A: Materials Science and Processing</i> , <b>2011</b> , 102, 785-789	2.6	128
15	Feedback write scheme for memristive switching devices. <i>Applied Physics A: Materials Science and Processing</i> , <b>2011</b> , 102, 973-982	2.6	63
14	Anatomy of a nanoscale conduction channel reveals the mechanism of a high-performance memristor. <i>Advanced Materials</i> , <b>2011</b> , 23, 5633-40	24	338
13	Spectromicroscopy of tantalum oxide memristors. <i>Applied Physics Letters</i> , <b>2011</b> , 98, 242114	3.4	77
12	Observation of two resistance switching modes in TiO <sub>2</sub> memristive devices electroformed at low current. <i>Nanotechnology</i> , <b>2011</b> , 22, 254007	3.4	62
11	Memristive switches enable stateful logic operations via material implication. <i>Nature</i> , <b>2010</b> , 464, 873-650.4	50.4	1405
10	High switching endurance in TaO <sub>x</sub> memristive devices. <i>Applied Physics Letters</i> , <b>2010</b> , 97, 232102	3.4	467
9	Direct identification of the conducting channels in a functioning memristive device. <i>Advanced Materials</i> , <b>2010</b> , 22, 3573-7	24	278

8	Memristor-CMOS hybrid integrated circuits for reconfigurable logic. <i>Nano Letters</i> , <b>2009</b> , 9, 3640-5	11.5	507
7	The mechanism of electroforming of metal oxide memristive switches. <i>Nanotechnology</i> , <b>2009</b> , 20, 215203-4	3.4	591
6	Switching dynamics in titanium dioxide memristive devices. <i>Journal of Applied Physics</i> , <b>2009</b> , 106, 074508-5	2.5	506
5	Memristive switching mechanism for metal/oxide/metal nanodevices. <i>Nature Nanotechnology</i> , <b>2008</b> , 3, 429-33	28.7	2239
4	2022 roadmap on neuromorphic computing and engineering. <i>Neuromorphic Computing and Engineering</i> ,		24
3	Timing Selector: Using Transient Switching Dynamics to Solve the Sneak Path Issue of Crossbar Arrays. <i>Small Science</i> ,2100072		8
2	A Dynamical Compact Model of Diffusive and Drift Memristors for Neuromorphic Computing. <i>Advanced Electronic Materials</i> ,2100696	6.4	6
1	Nonlinearity in Memristors for Neuromorphic Dynamic Systems. <i>Small Science</i> ,2100049		12